<u>TOSHIBA</u>

Unit: mm

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

TPC8124

Lithium Ion Battery Applications Power Management Switch Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: R_{DS} (ON) = 6.1 m Ω (typ.)
- Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -40 \ V)$
- Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_D = -0.5mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteri | stics | Symbol | Rating | Unit | |
|----------------------------|---------------------------|------------------|------------|------|--|
| Drain-source voltage | | V _{DSS} | -40 | V | |
| Drain-gate voltage (R | _{GS} = 20 kΩ) | V _{DGR} | -40 | V | |
| Gate-source voltage | | V _{GSS} | -25/+20 | V | |
| Drain current | DC (Note 1) | ۱ _D | -12 | А | |
| Diamounent | Pulse (Note 1) | I _{DP} | -48 | ~ | |
| Drain power dissipatio | n (t = 10 s) (Note 2a) | PD | 1.9 | W | |
| Drain power dissipatio | n (t = 10 s) (Note 2b) | PD | 1.0 | W | |
| Single pulse avalanch | e energy (Note 3) | E _{AS} | 134 | mJ | |
| Avalanche current (Note 1) | | I _{AR} | -12 | А | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature r | ange | T _{stg} | -55 to 150 | °C | |

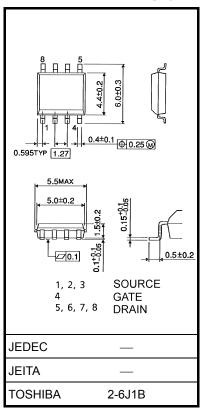
Note 1, Note 2, Note 3 : See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

temperature/current/voltage, etc.) are within the absolute maximum ratings.

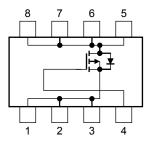
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.080 g (typ.)

Circuit Configuration

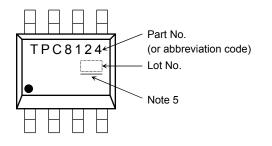


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Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|---|------------------------|------|------|
| Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2a) | R _{th (ch-a)} | 65.8 | °C/W |
| Thermal resistance, channel to ambient $(t = 10 s)$ (Note 2b) | R _{th (ch-a)} | 125 | °C/W |

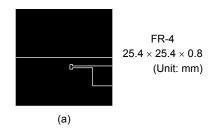
Marking (Note 4)

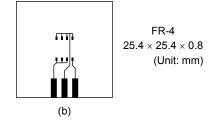


Note 1: Ensure that the channel temperature does not exceed 150 $^{\circ}\text{C}.$

Note 2: (a)Device mounted on a glass-epoxy board (a)

(b)Device mounted on a glass-epoxy board (b)





Note 3: $V_{DD} = -24$ V, $T_{ch} = 25$ °C (initial), L = 1.0 mH, $R_G = 25 \Omega$, $I_{AR} = -12$ A

Note 4: • on lower left of the marking indicates Pin 1.

* Weekly code: (Three digits)



Note 5: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Electrical Characteristics (Ta = 25°C)

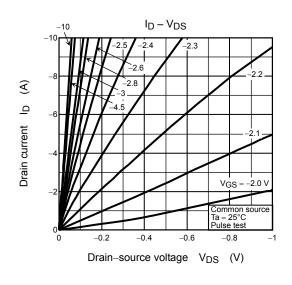
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|---------------|------------------|---|---------------------------------------|------|------|------|
| Gate leakage curre | ent | I _{GSS} | $V_{GS}=\pm 20~V,~V_{DS}=0~V$ | _ | _ | ±100 | nA |
| Drain cut-OFF curr | rent | I _{DSS} | $V_{DS} = -40 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | | _ | -10 | μA |
| Drain agurag brag | kdown voltogo | V (BR) DSS | $I_{D} = -10$ mA, $V_{GS} = 0$ V | -40 | | | v |
| Drain-source breat | kuown vollage | V (BR) DSX | $I_D = -10 \text{ mA}, V_{GS} = 10 \text{ V}$ (Note 6) | — — — — — — — — — — — — — — — — — — — | v | | |
| Gate threshold voltage | | V _{th} | $V_{DS} = -10 \text{ V}, \text{ I}_{D} = -0.5 \text{ mA}$ | -0.8 | | -2.0 | V |
| Drain-source ON-resistance | | D | $V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -6 \text{ A}$ | | 7.7 | 10 | mΩ |
| | | RDS (ON) | $V_{GS} = -10 \text{ V}, \text{ I}_{D} = -6 \text{ A}$ | | 6.1 | 8 | |
| Input capacitance | | C _{iss} | V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz | | 4750 | _ | pF |
| Reverse transfer capacitance | | C _{rss} | | _ | 540 | | |
| Output capacitance | | C _{oss} | | | 620 | | |
| $ \begin{array}{c c c c c c c c c c c c c c c c c c c $ | Rise time | tr | $V_{CS} = 0 V_{T} \Gamma = -6 A$ | | 9 | _ | |
| | | 20 | | | | | |
| | Fall time | t _f | $V_{DD} \approx -20 V$ | | 110 | _ | - ns |
| | Turn-OFF time | t _{off} | | _ | 390 | _ | |
| | | Qg | | _ | 104 | _ | |
| Gate-source charge 1 | | Q _{gs1} | | | 10 | | nC |
| <u> </u> | | Q _{gd} | | | 27 | | |

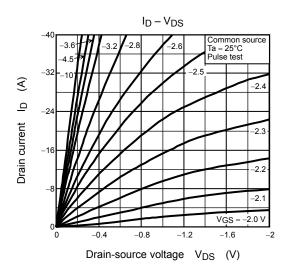
Source-Drain Ratings and Characteristics (Ta = 25°C)

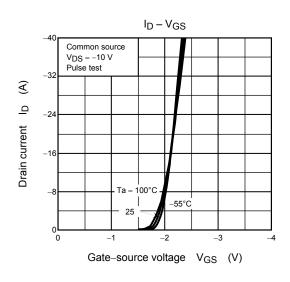
| Characteristics | | Symbol | Test Condition | Min | Тур. | Max | Unit | |
|-------------------------|-------|------------------|--|-----|------|-----|------|---|
| Drain reverse current | Pulse | (Note 1) | I _{DRP} | — | | _ | -48 | А |
| Forward voltage (diode) | | V _{DSF} | $I_{DR} = -12 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$ | _ | | 1.2 | V | |

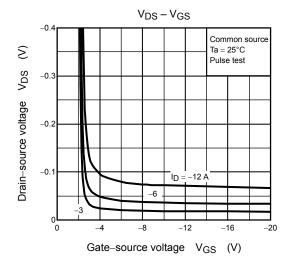
Note 6: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.

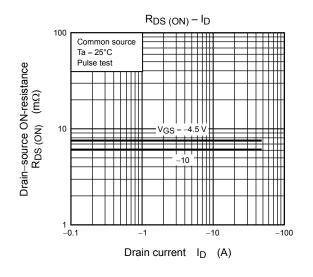
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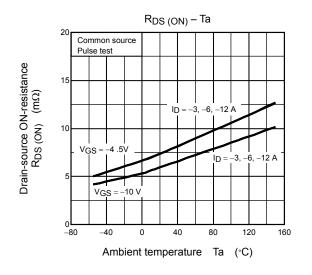


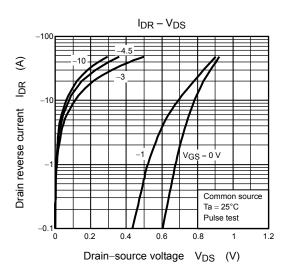


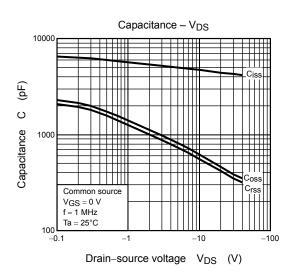


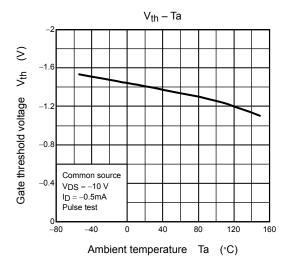


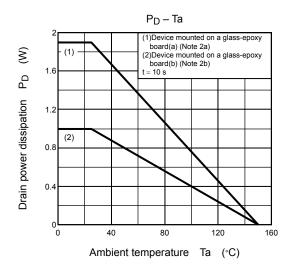
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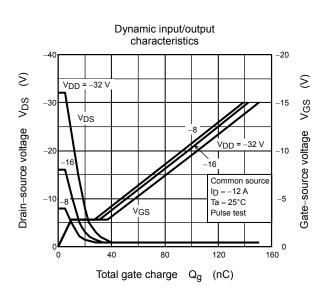


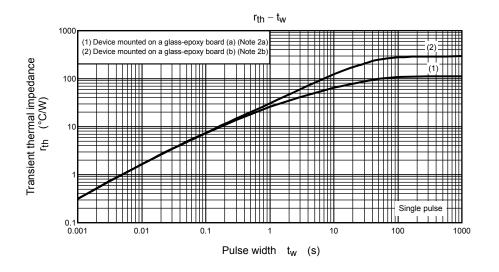


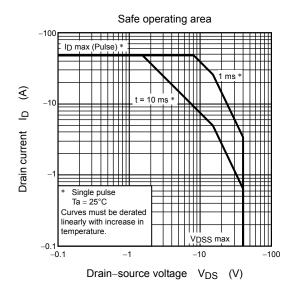












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